NSN 5961-01-333-0919

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-333-0919 **Inclosure Material:** Glass **Overall Length:** Between 0.100 inches and 0.170 inches **Terminal Length:** Between 0.975 inches and 1.500 inches **Overall Diameter:** Between 0.045 inches and 0.076 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case and quality assurance level tx **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 150.0 nonrepetitive peak reverse voltage, peak total value and 100.0 working peak reverse voltage, peak total value **Current Rating Per Characteristic:** 152.00 microamperes forward current, average absolute **Power Rating Per Characteristic:** 0.25 watts small-signal input power, common-collector of standard range **Capacitance Rating In Picofarads:** 0.3 **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** Nuclear hardness critical item; junction pattern arrangement: pin **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No